Diode Semiconductor Device - Page 1 of 1



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### **Inclosure Material:**

Metal

**Overall Diameter:** 

0.421 inches

Mounting Facility Quantity:

1

# Mounting Method:

Threaded stud

### **Features Provided:**

Hermetically sealed case

Thread Size:

0.180 inches

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

22.0 regulator voltage

**Current Rating Per Characteristic:** 

10.00 amperes source cutoff current preset

# **Power Rating Per Characteristic:**

10.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius case

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Thread Series Designator:**

Unf

Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

### **Specification Data:**

81349-mil-s19500/14/el government specification

#### Shelf Life:

N/a

### Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0

# Mil-std (military Standard):

Mil-prf-19500 spec.